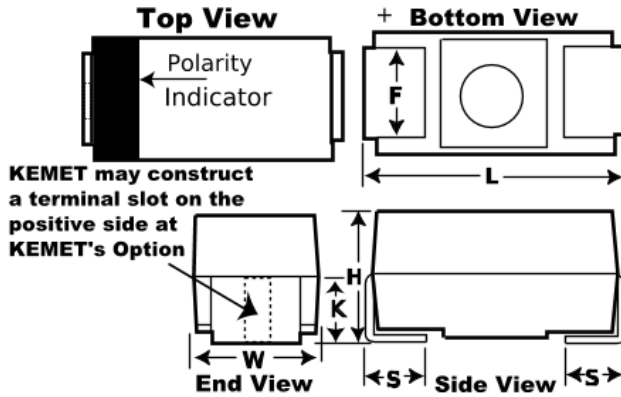


T495B336M006ZTA600

Obsolete

Tantalum, MnO₂ Tantalum, 33 uF, 20%, 6.3 VDC, SMD, Molded, Low ESR, Surge Robust, 600 mOhms, 3528, 2.1mm



General Information	
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, Molded, Low ESR, Surge Robust
Features	Low ESR, Surge Robust, Automotive
RoHS	Yes
Termination	Tin
AEC-Q200	No
Notes	Obsolete.

Specifications	
Capacitance	33 uF
Capacitance Tolerance	20%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.6 Ohms (100kHz)
Ripple Current	350 mAmps (25C), 315 mAmps (85C), 140 mAmps (125C)
Leakage Current	2.1 uA

Dimensions	
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.9mm +/-0.2mm
S	0.7mm +/-0.3mm
F	2.2mm +/-0.1mm
K	1.4mm TYP

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

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